
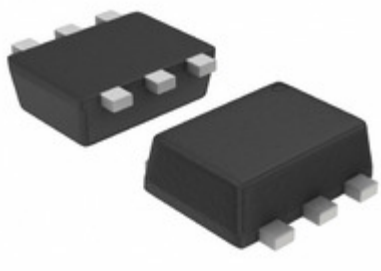

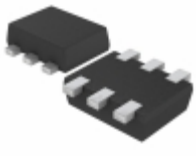






	<h2>EMX1DXV6T5G</h2>
	<p><b>Hersteller-Teilenummer:</b> <a href="#">EMX1DXV6T5G</a></p> <p><b>Hersteller / Marke:</b> <a href="#">AMI Semiconductor / ON Semiconductor</a></p> <p><b>Teil der Beschreibung:</b> TRANS 2NPN 50V 0.1A SOT563</p> <p><b>Datenblätter:</b>  <a href="#">EMX1DXV6T5G.pdf</a></p> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <p><b>Lagerzustand:</b> New original, 14065 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	<a href="#">EMX1DXV6T5G</a>
Hersteller	<a href="#">AMI Semiconductor / ON Semiconductor</a>
Beschreibung	TRANS 2NPN 50V 0.1A SOT563
Kategorie	<a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-bipolare</a>
Teilstatus	14065 pcs Stock
Serie	-
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Leistung - max	500mW
Verpackung / Gehäuse	SOT-563, SOT-666
Supplier Device-Gehäuse	SOT-563
Transistor-Typ	2 NPN (Dual)
Strom - Kollektor (Ic) (max)	100mA
Spannung - Kollektor-Emitter-Durchbruch (max)	50V
VCE Sättigung (Max) @ Ib, Ic	400mV @ 5mA, 50mA
Strom - Collector Cutoff (Max)	500nA (ICBO)
DC Stromgewinn (HFE) (Min) @ Ic, VCE	120 @ 1mA, 6V
Frequenz - Übergang	180MHz
Verpackung	Tape & Reel (TR)

EMX1DXV6T5G ist neu im Original, Suche EMX1DXV6T5G Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie EMX1DXV6T5G AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage EMX1DXV6T5G: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <p><b>EMX18GT2R</b> ROHM EMX18GT2R ROHM</p>	 <p><b>EMX1T2R</b> LAPIS Semiconductor TRANS 2NPN 50V 0.15A 6EMT</p>	 <p><b>EMX1FHAT2R</b> LAPIS Semiconductor NPN+NPN GENERAL PURPOSE AMPLIFIC</p>	 <p><b>EMX1N</b> ROHM ROHM SOT666</p>
 <p><b>EMX1DXV6T1G</b> AMI Semiconductor / ON Semiconductor TRANS 2NPN 50V 0.1A SOT563</p>	 <p><b>EMX1DXV6T1</b> AMI Semiconductor / ON Semiconductor TRANS 2NPN 50V 0.1A SOT563</p>	 <p><b>EMX1DXV6T5</b> ON EMX1DXV6T5 ON</p>	 <p><b>EMX1GT2R</b> /</p>

### heiße Teile

Mehr

<a href="#">06035C823KAT2A</a>	<a href="#">0603YC104MA19A</a>	<a href="#">1812AA222MAT1A\SB</a>	<a href="#">D 3DF300R07PE4_ENG</a>	<a href="#">AOZ1283PI</a>
<a href="#">APT5010B2FLL</a>	<a href="#">ATA6836C</a>	<a href="#">D BAT54-05E6327</a>	<a href="#">BQ2060A-E619</a>	<a href="#">BSV236SP</a>
<a href="#">BYT260PIV1000</a>	<a href="#">CCR40.0MXC7T</a>	<a href="#">CGA4J1X7S1C685K125AC</a>	<a href="#">CGJ4C2C0G1H272J060AA</a>	<a href="#">CS400-18io2</a>
<a href="#">D DG413FDY</a>	<a href="#">ELM9330AB-S</a>	<a href="#">EMX18GT2R</a>	<a href="#">EMX18T2R</a>	<a href="#">EMX1DXV6T1</a>
<a href="#">EMX1DXV6T1G</a>	<a href="#">EMX1DXV6T5</a>	<a href="#">EMX52T2R</a>	<a href="#">ESD23T15CA</a>	<a href="#">FDMA3023PZ</a>
<a href="#">FMC2G75US60</a>	<a href="#">FQD3P50TM</a>	<a href="#">D GJM0225C1E9R5CB01L</a>	<a href="#">GRM3166R1H121JZ01D</a>	<a href="#">IXDN404SIA</a>
<a href="#">KA78R33CTU</a>	<a href="#">D LT1208CS8</a>	<a href="#">LTC1773EMS</a>	<a href="#">MAX1748EUE-T</a>	<a href="#">MCC72-12ioB</a>
<a href="#">P214CH03CH0</a>	<a href="#">PVDZ172NS-T</a>	<a href="#">RT7291BGQUF</a>	<a href="#">SIT8008BI-73-18E</a>	<a href="#">SKM200GB126DE</a>
<a href="#">SKT340/06E</a>	<a href="#">SP3012-06UTG</a>	<a href="#">T508N18TOC</a>	<a href="#">D TC7S00FV</a>	<a href="#">TCET1102GD</a>
<a href="#">TD62003F-TP1</a>	<a href="#">TMP106YZCT</a>	<a href="#">TPS72216DBVR</a>	<a href="#">TW6802B-JPA2-GR</a>	<a href="#">VE-26Z-IY</a>

Contact us:[Info@Y-IC.com](mailto:Info@Y-IC.com)

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